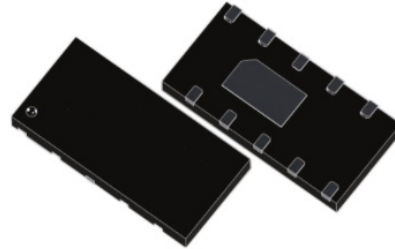


Features

- 30Watts peak pulse power ($t_p = 8/20\mu s$)
- Tiny DFN4120 package
- Protect up to 6-lines
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Low capacitance ($C_j=0.2pF$ typ. I/O to I/O)
- IEC 61000-4-2 $\pm 8kV$ contact $\pm 15kV$ air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 3A (8/20 μs)



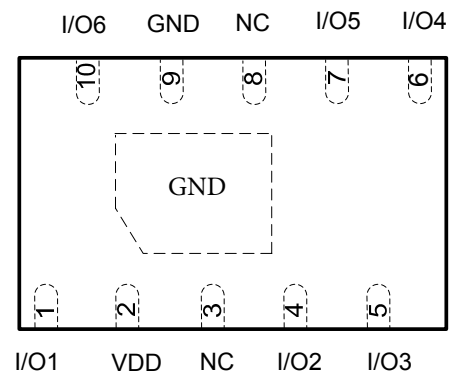
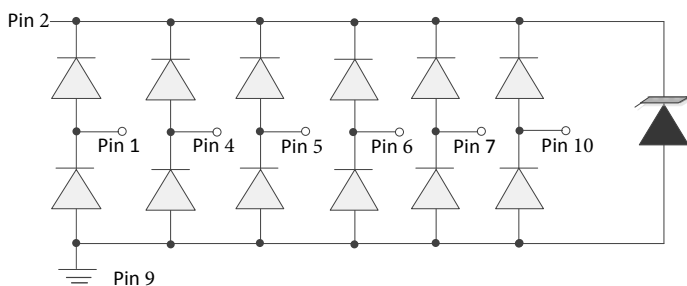
Applications

- USB 3.0/3.1, Type C
- HDMI 1.4/2.0, Display Port 1.3
- Unified Display interface
- Digital visual interface

Mechanical Data

- DFN4120 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

Schematic & PIN Configuration



Absolute Maximum Rating

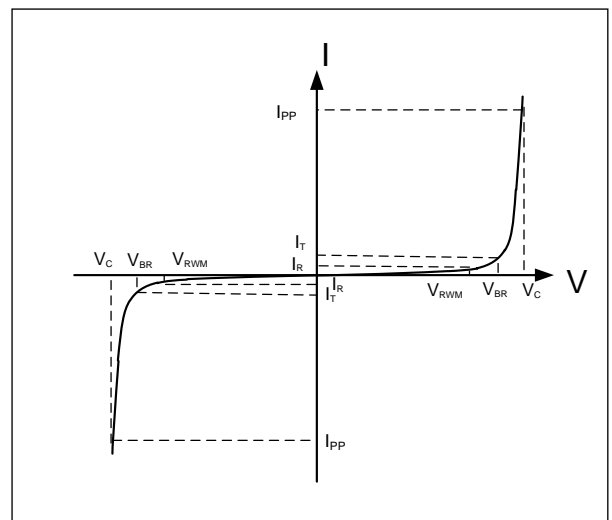
Rating	Symbol	Value	Units
Peak Pulse Power ($t_p = 8/20\mu s$)	P_{PP}	30	Watts
Peak Pulse Current ($t_p = 8/20\mu s$) (note1)	I_{PP}	3	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V_{ESD}	15 8	kV
Lead Soldering Temperature	T_L	260(10seconds)	°C
Junction Temperature	T_J	-55 to + 125	°C
Storage Temperature	T_{stg}	-55 to + 125	°C

Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				5.0	V
Reverse Breakdown Voltage	V_{BR}	$I_T = 1mA$	6.0	7.2	9.5	V
Reverse Leakage Current	I_R	$V_{RWM} = 5V, T = 25^\circ C$		0.1	0.5	μA
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu s$			3	A
Clamping Voltage	V_C	$I_{PP} = 3A, t_p = 8/20\mu s$			10	V
Junction Capacitance	C_j	$V_R = 0V, f = 1MHz$ I/O to I/O		0.2		pF
		$V_R = 0V, f = 1MHz$ I/O to GND		0.4		pF

Electrical Parameters (TA = 25°C unless otherwise noted)

Symbol	Parameter
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current



Note: 8/20 μs pulse waveform.



Typical Characteristics

Fig.1 IEC61000-4-2 Waveform

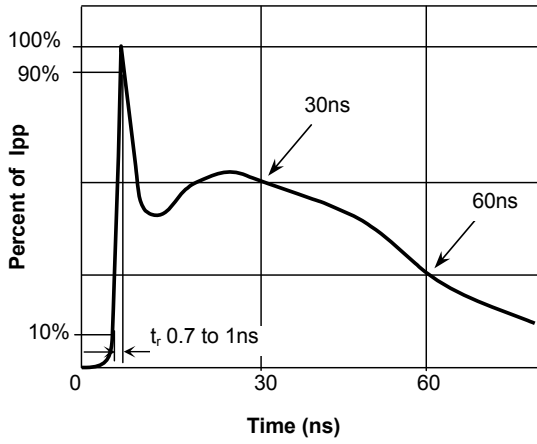


Fig.2 IEC61000-4-2 +8kV Contact ESD Clamping Waveform

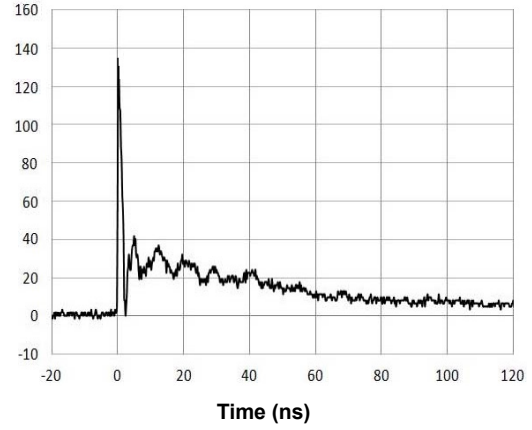


Fig.3 Eye Diagram - USB3.1 at 10Gbps per channel

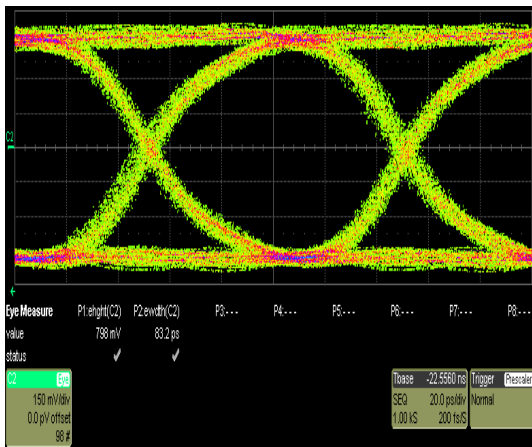
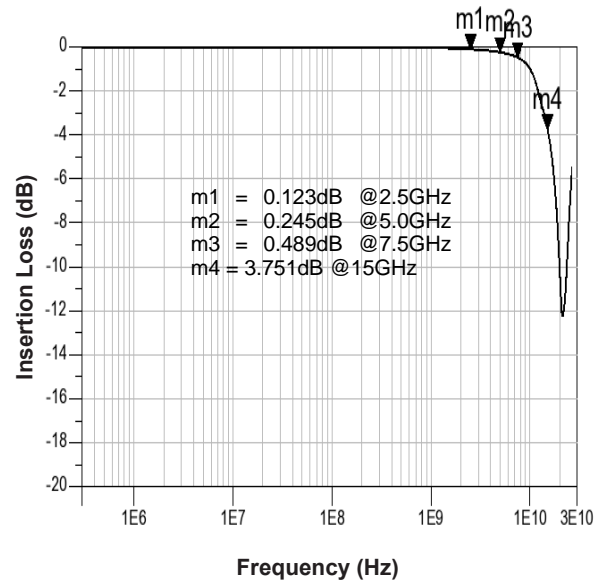
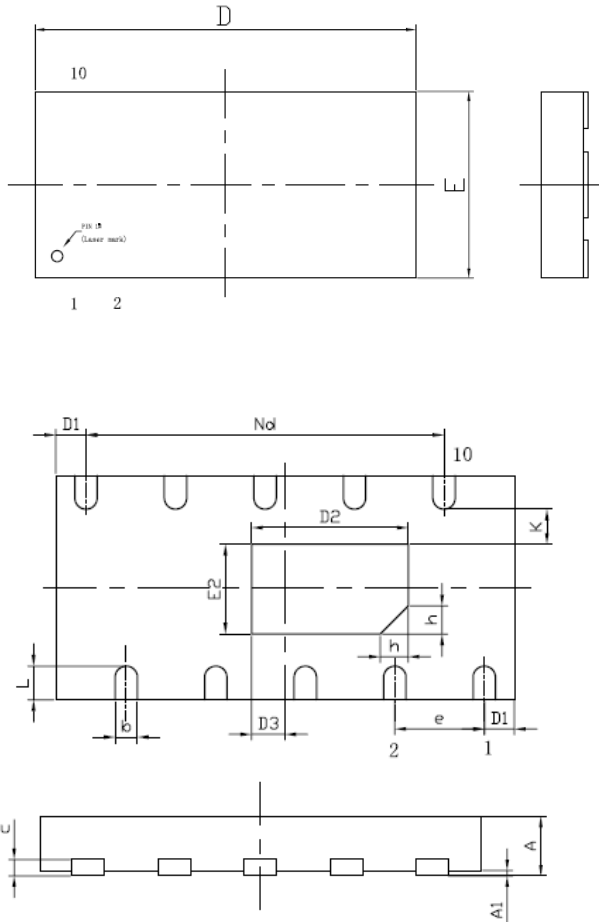


Fig.4 Insertion Loss S21 - I/O to I/O



Outline Drawing – DFN4120



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	0.45	0.50	0.55
A1	—	0.02	0.05
b	0.15	0.20	0.25
c	0.10	0.15	0.20
D	4.00	4.10	4.20
D1	0.20	0.25	0.30
D2	1.30	1.40	1.50
D3	0.25	0.30	0.35
e	0.80BSC		
Nd	3.20BSC		
E	1.90	2.00	2.10
E2	0.70	0.80	0.90
K	0.20	—	—
L	0.25	0.30	0.35
h	0.15	0.20	0.25
L/F载体尺寸 (MIL)	67*43		

Marking



Ordering information

Order code	Package	Base qty	Delivery mode
RL412010Q0507LV	DFN4120	3000	Tape and reel

